

# **Agilent HSDL-9100 Miniature Surface-Mount Proximity Sensor** Data Sheet

# Description

The HSDL-9100 is an analogoutput reflective sensor with an integrated high efficiency infrared emitter and photodiode housed in a small form factor SMD package. The optical proximity sensor is housed in a specially designed metal-shield to ensure excellent optical isolation resulting in low optical crosstalk.

HSDL-9100 is a class of its own with its small form SMD package and at a detection range from near zero to 60mm. It is specifically optimized for size, performance and ease of design in mobile constrained applications such as mobile phones and notebooks.

HSDL-9100 has extremely low dark current and high signal to noise ratio (SNR) where high SNR is achieved with a pair of highly efficient infrared emitter and highly sensitive detector.



#### **Application Support Information**

The Application Engineering Group is available to assist you with the application design associated with HSDL-9100 Proximity Sensor. You can contact them through your local sales representatives for additional details.

# **Order Information**

Part Number(HSDL-9100-021)Packaging Type(Tape and Reel)Package(PCB Substrate,moulded packageQuantityQuantity(2500 units)

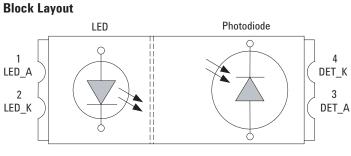
#### Features

- Excellent optical isolation resulting in near zero optical cross-talk
- High efficiency emitter and high sensitivity photodiode for high signal-to-noise ratio
- Low cost & lead-free miniature surface-mount package Height – 2.70 mm Width – 2.75 mm Length – 7.10 mm
- Detect objects from near zero to 60mm
- Low dark current
- Guaranteed Temperature Performance -40°C to 85°C

# Applications

- Mobile phones
- Notebooks
- Industrial Control
- Printers, Photocopiers and Facsimile machines
- Home Appliances
- Vending Machines





TOP VIEW

Figure 1. Block Layout of HSDL-9100

# **Pins Configuration Table**

| Pin    | Symbol | Description        | Notes |
|--------|--------|--------------------|-------|
| 1      | LED_A  | LED Anode          | 1     |
| 2      | LED_K  | LED Cathode        | -     |
| 3      | DET_A  | Photodiode Anode   | -     |
| 4      | DET_K  | Photodiode Cathode | -     |
| Notes: |        |                    |       |

Voltage to supply across the LED; VLED

# Absolute Maximum Ratings (Ta=25°C)

|   |                  | Ratings |      |       |
|---|------------------|---------|------|-------|
| Parameter                                   | Symbol           | Min.    | Max  | Units |
| Emitter                                     |                  |         |      |       |
| Continuous Forward Current                  | I <sub>DC</sub>  | -       | 50   | mA    |
| Coupled                                     |                  |         |      |       |
| Total Power Dissipation (refer to Figure 1) | Ρ <sub>τοτ</sub> | -       | 165  | mW    |
| Operating Temperature                       | T <sub>OP</sub>  | -40     | +85  | °C    |
| Storage Temperature                         | T <sub>STG</sub> | -40     | +100 | °C    |
| Reflow Soldering Temperature                | T <sub>SOL</sub> | -       | 260  | °C    |

# Electrical-Optical Characteristics (Ta=25°C)

|                              |                   |                               | Ratings |      |      |       |
|------------------------------|-------------------|-------------------------------|---------|------|------|-------|
| Parameter                    | Symbol            | Test Condition                | Min     | Тур  | Max  | Units |
| Emitter                      |                   |                               |         |      |      |       |
| Forward Voltage              | VF                | I <sub>F</sub> = 100mA        | _       | 1.50 | 1.65 | V     |
| Reverse Voltage              | V <sub>R</sub>    | $I_R = 10 uA$                 | 5       | _    | _    | V     |
| Peak Wavelength              | $\lambda_p$       | $I_F = 20 \text{mA}$          | _       | 940  | _    | nm    |
| Spectrum Width of Half Value | $\Delta_{p}$      | I <sub>F</sub> = 20mA         | _       | 50   | -    | nm    |
| Detector                     |                   |                               |         |      |      |       |
| Dark Current                 | I <sub>Dark</sub> | $V_{\rm B} = 10V, L^{**} = 0$ | _       | 2    | 10   | nA    |
| Forward Voltage              | VF                | I <sub>F</sub> = 10mA , L=0   | 0.5     | _    | 1.3  | V     |
| Reverse Breakdown Voltage    | V <sub>BR</sub>   | $I_{R} = 100 uA, L = 0$       | -       | -    | 35   | V     |
| Coupled                      |                   |                               |         |      |      |       |
| Output Current               | I <sub>o</sub>    | Refer to Fig 2                | _       | 0.1  | _    | mΑ    |
| Peak Output Distance         | Do                | Refer Note 1                  | _       | 5    | -    | mm    |
| Operating Cross Talk Current | I <sub>FD</sub>   | Refer to Fig 3                | _       | _    | 200  | nA    |
| Rise Time (LED)              | T <sub>RL</sub>   | $R_L = 50\Omega$              | _       | 50   | -    | ns    |
| Fall Time (LED)              | $T_{FL}$          | $R_L = 50\Omega$              | _       | 50   | -    | ns    |
| Rise Time (Photodiode)       | T <sub>RD</sub>   | $R_L = 5.1 K\Omega$           | _       | 6    | -    | μs    |
| Fall Time (Photodiode)       | T <sub>RD</sub>   | $R_L = 5.1 K\Omega$           | _       | 6    | _    | μs    |

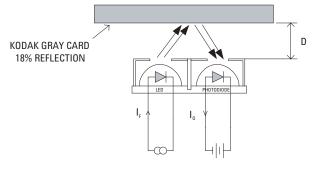
\*\* L = 0 (zero light condition)

Note:

1.  $I_{Led} = 300 \text{mA}$  Pulse, 5% Duty Cycle

(Kodak 18% Reflectance Gray Card)

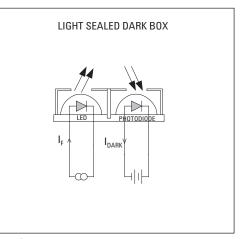
# Output Current Test Condition (Ta=25°C)



# Figure 2.

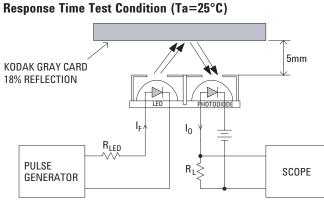
Test Condition used are D = 5mm 18% Gray Card,  $I_{LED}$  = 300mA Pulse, 5% Duty Cycle

# Dark Current Test Condition (Ta=25°C)

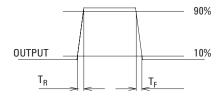


# Figure 3.

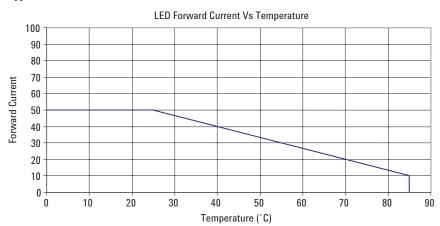
Test Condition used are  $I_{LED}$  = 300mA Pulse, 5% Duty Cycle



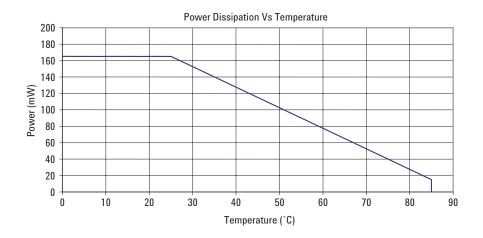




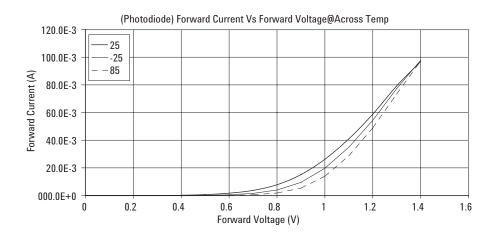


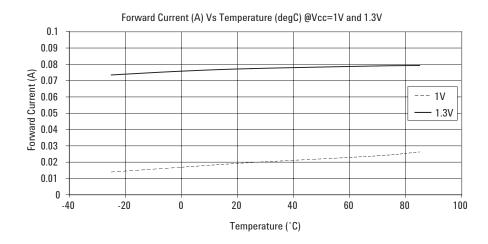


# **Typical Characteristics**

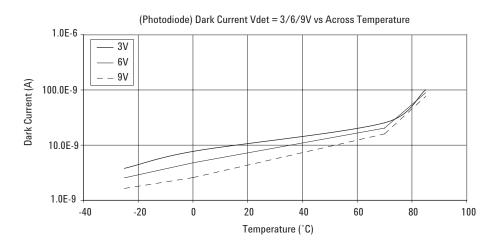


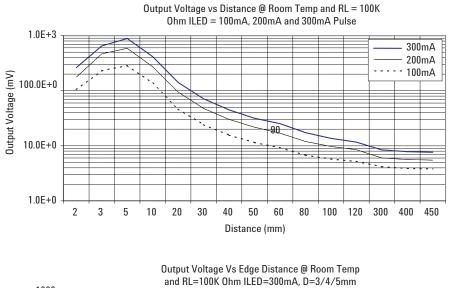
LED Forward Current Vs Forward Voltage @ Across Temperature 0.12 25 0.1 85 Forward Current (A) 0.08 0.06 0.04 0.02 0 0 0.2 0.4 0.6 1.2 1.4 0.8 1 1.6 Forward Voltage (V)

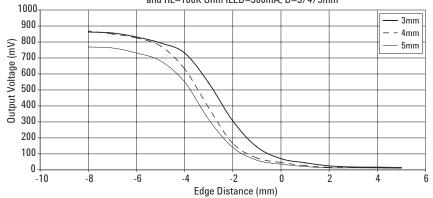




(Photodiode) Rise/Fall Time Vs Load Resistance@Room Temp, ILED=300mA Pulse 1.0E+3 900.0E+0 --- (Rise) (Fall) 800.0E+0 Response Time (us) 700.0E+0 600.0E+0 Mean (Fall) 500.0E+0 400.0E+0 300.0E+0 200.0E+0 100.0E+0 000.0E+0 0.1 1 10 100 1000 10000 Load Resistance (kohm)







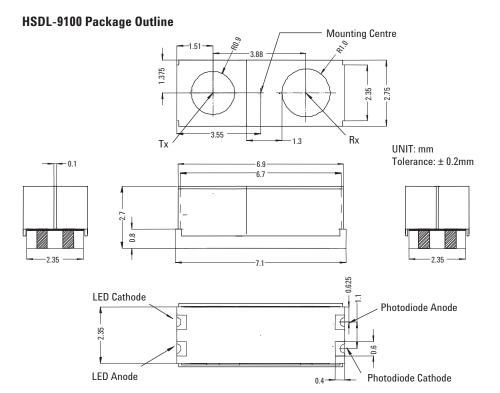
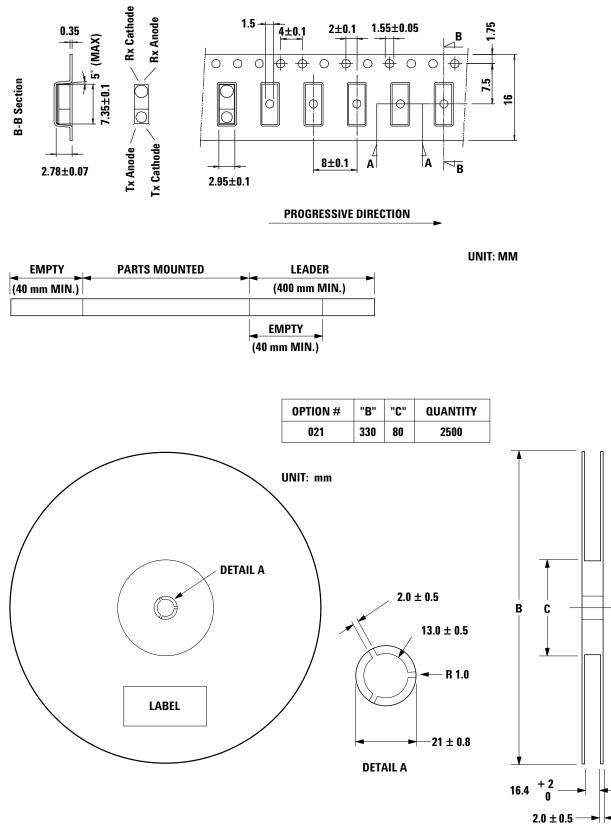


Figure 5. Package outline dimensions

# HSDL-9100-021 Tape and Reel Dimensions





# HSDL-9100 Moisture Proof Packaging

All HSDL-9100 options are shipped in moisture proof package. Once opened, moisture absorption begins.

This part is compliant to JEDEC Level 4.

## **Baking Conditions**

If the parts are not stored in dry conditions, they must be baked before reflow to prevent damage to the parts.

| Package  | Temp   | Time           |  |
|----------|--------|----------------|--|
| In reels | 60 °C  | $\geq$ 48hours |  |
| In bulk  | 100 °C | $\geq$ 4hours  |  |
|          | 125 °C | $\geq$ 2 hours |  |
|          | 150 °C | $\geq$ 1 hour  |  |

Baking should only be done once.

# **Recommended Storage Conditions**

| Storage<br>Temperature | 10°C to 30°C |  |  |
|------------------------|--------------|--|--|
| Relative Humidity      | below 60% RH |  |  |

#### Time from unsealing to soldering

After removal from the bag, the parts should be soldered within three days if stored at the recommended storage conditions. If times longer than three days are needed, the parts must be stored in a dry box.

# **Baking Conditions Chart**

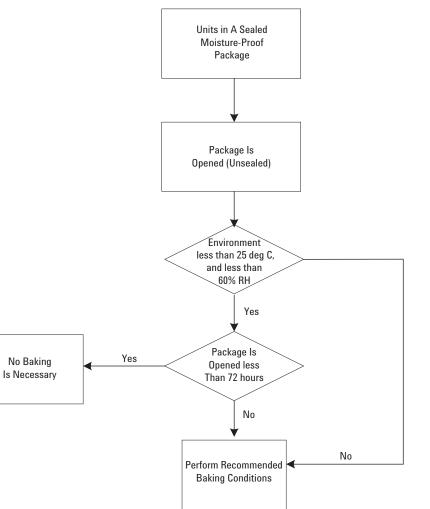


Figure 7. Baking conditions chart

#### **Recommended Reflow Profile**

The reflow profile is a straight-line representation of a nominal temperature profile for a convective reflow solder process. The temperature profile is divided into four process zones, each with different DT/Dtime temperature change rates. The DT/Dtime rates are detailed in the above table. The temperatures are measured at the component to printed circuit board connections.

In process zone P1, the PC board and HSDL-9100 castellation pins are heated to a temperature of 160°C to activate the flux in the solder paste. The temperature ramp up rate, R1, is limited to 4°C per second to allow for even heating of both the PC board and HSDL-9100 castellations.

Process zone P2 should be of sufficient time duration (60 to 120 seconds) to dry the solder paste. The temperature is raised to a level just below the liquidus point of the solder, usually 200°C (392°F).

Process zone P3 is the solder reflow zone. In zone P3, the temperature is quickly raised above the liquidus point of solder to 255°C (491°F) for optimum results. The dwell time above the liquidus point of solder should be between 20 and 60 seconds. It usually takes about 20 seconds to assure proper coalescing of the solder balls into liquid solder and the formation of good solder connections. Beyond a dwell time of 60 seconds, the intermetallic growth within the solder connections becomes excessive, resulting in the formation of weak and unreliable connections. The temperature is then rapidly reduced to a point below the solidus temperature of the solder, usually 200°C (392°F), to allow the solder within the connections to freeze solid.

Process zone P4 is the cool down after solder freeze. The cool down rate, R5, from the liquidus point of the solder to 25°C (77°F) should not exceed 6°C per second maximum. This limitation is necessary to allow the PC board and HSDL-9100 castellations to change dimensions evenly, putting minimal stresses on the HSDL-9100 transceiver.

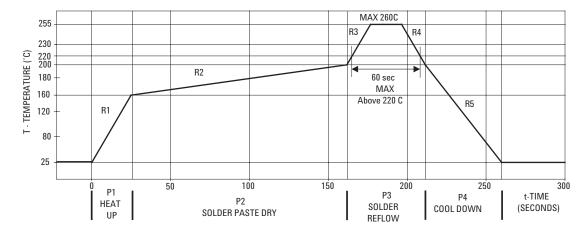


Figure 8. Reflow graph

| Process Zone     | Symbol       | ΔΤ   | Maximum $\Delta T / \Delta time$ |
|------------------|--------------|--|----------------------------------|
| Heat Up          | P1, R1       | 25°C to 160°C  | 4°C/s                            |
| Solder Paste Dry | P2, R2       | 160°C to 200°C   | 0.5°C/s                          |
| Solder Reflow    | P3, R3P3, R4 | 200°C to 255°C (260°C at 10 seconds max)<br>255°C to 200°C | 4°C/s<br>-6°C/s                  |
| Cool Down        | P4, R5       | 200°C to 25°C  | -6°C/s                           |

#### Appendix A: HSDL-9100 SMT Assembly Application Note

# Recommended Metal solder Stencil Aperture

It is recommended that only a 0.152 mm (0.006 inch) or a 0.127 mm (0.005 inch) thick stencil be used for solder paste printing. This is to ensure adequate printed solder paste volume and no shorting. See Table 1 below the drawing for combinations of metal stencil aperture and metal stencil thickness that should be used. Aperture opening for shield pad is 3.05 mm x 1.1 mm as per land pattern.

# Table 1. Combinations of metalstencil aperture and metal stencilthickness

| Stencil              | Aperture size (mm) |             |  |
|----------------------|--------------------|-------------|--|
| thickness,<br>t (mm) | Length,<br>I       | Width,<br>w |  |
| 0.152                | 1.60+/-0.05        | 0.55+/-0.05 |  |
| 0.127                | 1.92               | 0.55+/-0.05 |  |

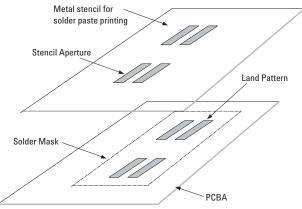
# Adjacent Land Keep out and Solder Mask Areas

Adjacent land keep out is the maximum space occupied by the unit relative to the land pattern. There should be no other SMD components within this area. The minimum solder resist strip width required to avoid solder bridging adjacent pads is 0.2mm.It is recommended that two fiducial crosses be placed at mid length of the pads for unit alignment. Also do take note that there should not be any electrical routing with the component placement compartment.

#### Note:

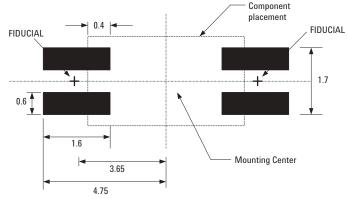
Wet/Liquid Photo-imaginable solder resist/ mask is recommended

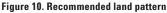
#### Solder Pad, Mask and Metal Stencil

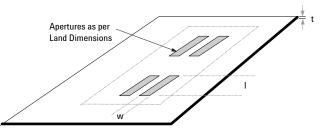




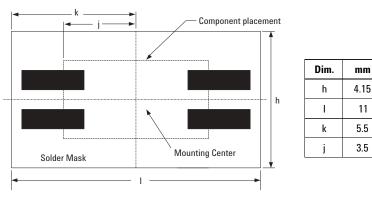
# **Recommended land pattern**







#### Figure 11. Solder stencil aperture





#### **Appendix B: General Application Guide for the HSDL-9100**

#### Description

The Proximity sensor has several possible applications for multimedia product, Automation, and Personal handled. The proximity sensor is basically made up of the emitter (infrared LED) and detector (photodiode). The block diagram of the sensor is shown in Figure 13. The emitter will emit IR light pulse. This light travels out in the field of view and will either hit an object or continue. No light will be reflected when no object is

detected. On the other hand, the detector will detect the reflected IR light when it hits the object.

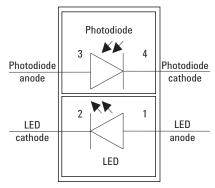
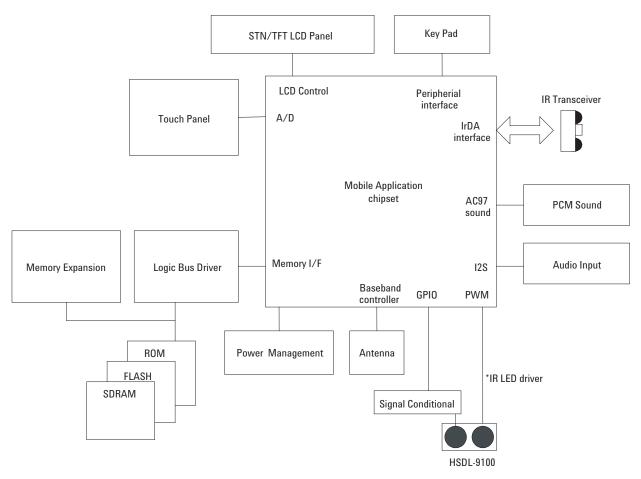


Figure 13. Proximity sensor block diagram (refer to Pins Configuration Table)

# Interface to the Recommended I/O chip

The HSDL-9100 is general interface with the GPIO pin of the controller chipset. The LED\_A, pin1 is connected to the PWM port alternatively the external timer circuitry can be used to drive the LED. The DET\_K, pin 4 is interface to the signal conditioning before driving the GPIO port.

Figure 14 shows the hardware reference design with HSDL-9100.



\* The LED can be driven by the PWM output or the external timer circuitry. Figure 14. Mobile Application Platform

The next section discusses interfacing configuration with general processor including the recommended signal conditional circuitry.

The DET\_K pin of HSDL-9100 is connected to the filter circuit then to the comparator before interfacing with the GPIO pin. The filter circuit is implement to provide the ambient light filter. The PWM is pulse to drive the LED\_K pin alternative the external timer 555 can also be replaced. The detector distance can be varies with the increase/decrease of the LED current supply.

#### Interfacing circuitry with signal conditional circuitry

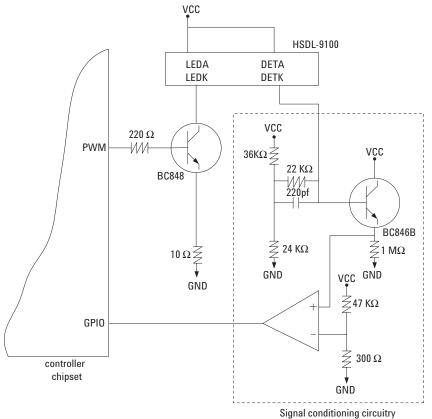


Figure 15. HSDL9100 configuration with controller chipset

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